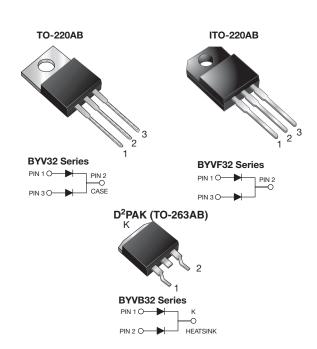


Vishay General Semiconductor

Dual Common-Cathode Ultrafast Rectifier



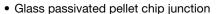
DESIGN SUPPORT TOOLS AVAILABLE



PRIMARY CHARACTERISTICS							
I _{F(AV)}	18 A						
V _{RRM}	50 V to 200 V						
I _{FSM}	150 A						
t _{rr}	25 ns						
V _F	0.85 V						
T _J max.	150 °C						
Package	TO-220AB, ITO-220AB, D ² PAK (TO-263AB)						
Circuit configuration	Common cathode						

FEATURES

Power pack





- · Ultrafast recovery time
- · Low switching losses, high efficiency
- Low forward voltage drop
- · High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 275 °C max. 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified available
 - Automotive ordering code: base P/NHE3 (for ITO-220AB and D2PAK (TO-263AB package))
- · Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, inverters, freewheeling diodes, DC/DC converters, and other power switching application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, D2PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3_X - RoHS-compliant and AEC-Q101 qualified ("_X" denotes revision code e.g. A, B,...)

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs max.

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	BYV32-50	BYV32-100	BYV32-150	BYV32-200	UNIT	
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	150	200	V	
Maximum RMS voltage	V _{RMS}	35	70	105	140	V	
Maximum DC blocking voltage	V_{DC}	50	100	150	200	V	
Maximum average forward rectified current at T _C = 125 °C	I _{F(AV)}	18			Α		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	150			А		
Operating storage and temperature range	T_J , T_{STG}	-65 to +150			°C		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500			V		



BYV32-xxx, BYVF32-xxx, BYVB32-xxx

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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)								
PARAMETER	TEST CO	NDITIONS	SYMBOL	BYV32-50 BYV32-100 BYV32-150 BYV32-2		BYV32-200	UNIT	
Maximum instantaneous forward	I _F = 20 A	T _J = 25 °C	V _E ⁽¹⁾ 1.15			V		
voltage per diode	_F = 5.0 A	T _J = 100 °C	v _F ···	0.85		.85	5	
Maximum DC reverse current		T _J = 25 °C		10				μA
per diode at rated DC blocking voltage		T _J = 100 °C	I _R	600				
Maximum reverse recovery time per diode	I _F = 1 A, V _R = 3 dI/dt = 100 A/ ₁	30 V us, I _{rr} = 10 % I _{RM}	t _{rr}	25				ns
Typical junction capacitance per diode	4.0 V, 1 MHz		CJ	45			pF	

Note

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER		BYV	BYVF	BYVB	UNIT	
Typical thermal resistance from junction to case per diode	$R_{\theta JC}$	1.6	5.0	1.6	°C/W	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	BYV32-200-E3/45	1.85	45	50/tube	Tube			
ITO-220AB	BYVF32-200-E3/45	1.97	45	50/tube	Tube			
TO-263AB	BYVB32-200-E3/45	1.35	45	50/tube	Tube			
TO-263AB	BYVB32-200-E3/81	1.35	81	800/reel	Tape and reel			
ITO-220AB	BYVF32-200HE3_A/P (1)	1.97	Р	50/tube	Tube			
TO-263AB	BYVB32-200HE3_A/P (1)	1.35	Р	50/tube	Tube			
TO-263AB	BYVB32-200HE3_A/I (1)	1.35	I	800/reel	Tape and reel			

Note

⁽¹⁾ AEC-Q101 qualified, available in ITO-220AB and TO-263AB package

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

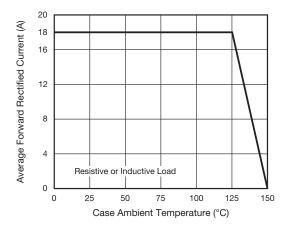


Fig. 1 - Forward Current Derating Curve

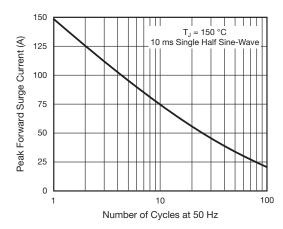


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

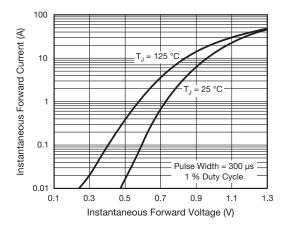


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

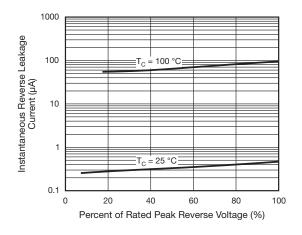


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

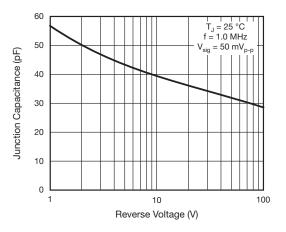
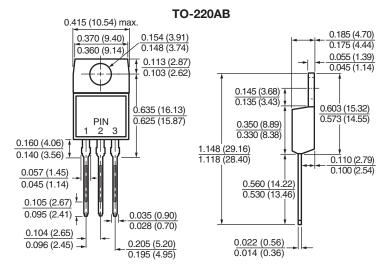


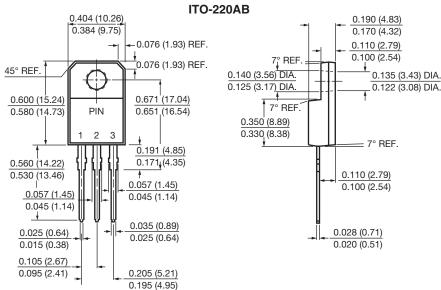
Fig. 5 - Typical Junction Capacitance Per Diode



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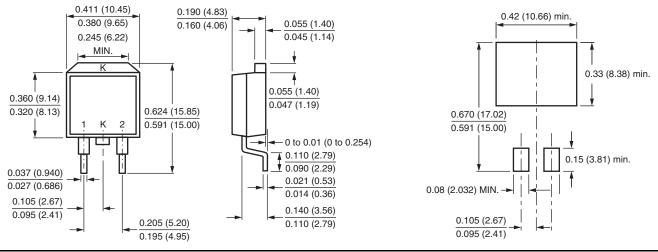
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





D²PAK (TO-263AB)

Mounting Pad Layout





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